VS-UFB80FA40

Vishay Semiconductors

Insulated Ultrafast Rectifier Module, 80 A



www.vishay.com

SOT-227

400 V

80 A

32 ns

Modules - Diode FRED Pt®

PRODUCT SUMMARY

 V_R

I_{F(AV)} per module at T_C = 121 °C

t_{rr} Type

FEATURES

- Two fully independent diodes
- · Fully insulated package
- Ultrafast, soft reverse recovery, with high operation junction temperature (T_J max. = 175 °C)
 RoHS
 COMPLIANT
- Low forward voltage drop
- Optimized for power conversion: welding and industrial SMPS applications
- Easy to use and parallel
- Industry standard outline
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

The VS-UFB80FA40 insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The diodes structure, and its life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	V _R		400	V			
Continuous forward current per diode	١ _F	T _C = 130 °C	40	^			
Single pulse forward current per diode	I _{FSM}	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	270	A			
Maximum power dissipation per module	PD	T _C = 130 °C	90	W			
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 min	2500	V			
Operating junction and storage temperatures	T _J , T _{Stg}		- 55 to 175	°C			

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA	400	-	-		
Forward voltage	V _{FM}	I _F = 30 A	-	1.14	1.39	V	
		I _F = 30 A, T _J = 175 °C	-	0.91	1.04		
	I _{RM}	$V_{R} = V_{R}$ rated	-	-	50	μA	
Reverse leakage current		$T_J = 175 \text{ °C}, V_R = V_R \text{ rated}$	-	-	1	mA	
Junction capacitance	CT	V _R = 200 V	-	68	-	pF	

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONE	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	32	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	68	-	ns A	
		T _J = 125 °C		-	125	-		
De els vie e este en entre est		T _J = 25 °C	I _F = 30 A dI _F /dt = 200 A/μs V _B = 200 V	-	6.8	-		
Peak recovery current	I _{RRM}	T _J = 125 °C		-	15	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	215	-	nC	
		T _J = 125 °C		-	900	-	10	

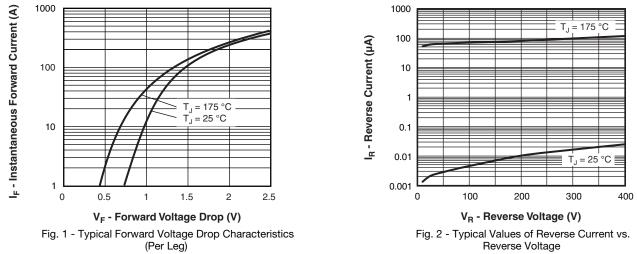
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Junction to case, single leg conducting	В		-	-	1.0		
Junction to case, both leg conducting	R _{thJC}		-	-	0.50	°C/W	
Case to heatsink	R _{thCS}	Flat, greased surface	-	0.10	-		
Weight			-	30	-	g	
Mounting torque			-	1.3	-	Nm	
Case style			SOT-227				

2 For technical questions, contact: <u>DiodesAmericas@vishay.com</u>



Vishay Semiconductors





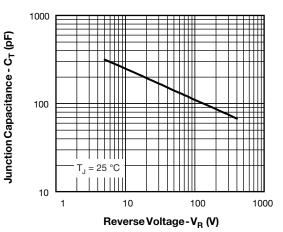


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

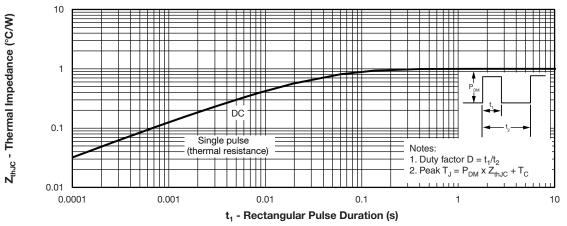
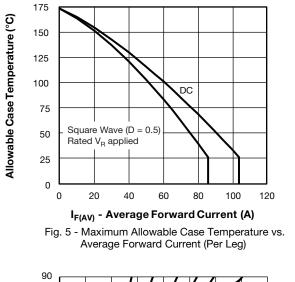


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

Downloaded from Elcodis.com electronic components distributor

Vishay Semiconductors



www.vishay.com

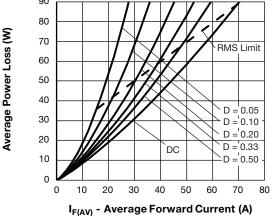
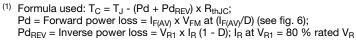
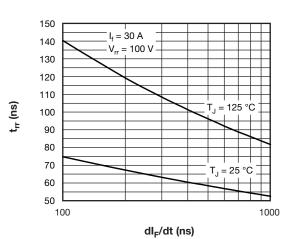


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

Note







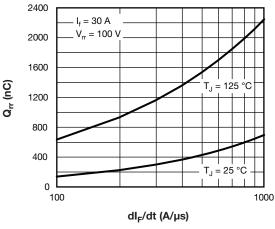


Fig. 8 - Typical Stored Charge vs. dl_F/dt

VS-UFB80FA40

Vishay Semiconductors



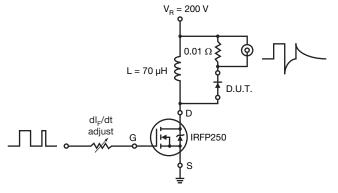
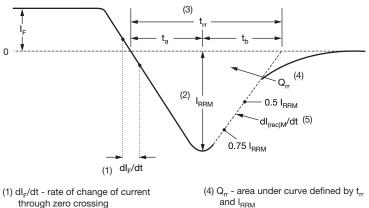


Fig. 9 - Reverse Recovery Parameter Test Circuit



- through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going ${\rm I}_{\rm F}$ to point where a line passing through 0.75 $I_{\rm RRM}$ and 0.50 $I_{\rm RRM}$ extrapolated to zero current.
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$ (5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}
- Fig. 10 Reverse Recovery Waveform and Definitions

Vishay Semiconductors



ORDERING INFORMATION TABLE

Device code	VS-	UF	В	80	F	Α	40	
	1	2	3	4	5	6	7	
	1 -	Visł	nay Sem	niconduc	ctors pro	oduct		
	2 -	Ultr	Ultrafast rectifier					
	3 -	Ultr	Ultrafast Pt diffused					
	4 -	Cur	Current rating (80 = 80 A)					
	5 -	Circuit configuration (2 separate diodes, parallel pin-ou						
	6 -	Pac	Package indicator (SOT-227 standard isolated base)					
	7 -	Volt	age rati	ng (40 =	= 400 V)	1		

CIRCUIT CONFIGURATION						
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
2 separate diodes, parallel pin-out	F	Lead Assignment 4 4 1 1 1 1 1 1 1 1 1 1 1 1 1				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95423					
Packaging information	www.vishay.com/doc?95425				



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.